Application Report
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# Cut-Off Switch in High-Current Motor-Drive Applications

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**ABSTRACT**

Some motor drive applications with high-current motors require power switches to decrease quiescent current or to get an alternate load turnoff path. Because the system output power is very high, discrete pass elements must be implemented. This document describes different topologies for implementing a "cut-off switch."

**Contents**

1 Introduction ..... 1
2 The Discrete PMOS Cut-Off Switch ..... 2
3 The Discrete NMOS Cut-Off Switch ..... 2
4 The Upstream NMOS Cut-Off Switch ..... 3
5 The NMOS Cut-Off Switch With Downstream Motor Driver ..... 4
6 References ..... 5

**List of Figures**

1 Cut-Off Switch ..... 2
2 Discrete PMOS Cut-Off Switch ..... 2
3 Discrete NMOS Cut-Off Switch ..... 3
4 Upstream NMOS Cut-Off Switch ..... 3
5 NMOS Cut-Off Switch With Downstream Motor Driver ..... 4

**List of Tables**

1 Device Options ..... 3
2 Device Options ..... 4

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## 1 Introduction

A power switch is an electronic relay designed to prevent the flow of current in a system and is located between some load circuit and the system supply. Any power-consuming circuit can be a load. A system supply can be an AC/DC generated regulated voltage (12 V, 24 V, 48 V, and so forth) or a battery (lead acid, lithium ion, nickel cadmium, or other battery types). For a more detailed look at different power switch topologies and solutions, see the *Basics of Power Switches* application report.

Power switches have several uses in both regulated supply and battery-powered applications:

- To decrease quiescent current in standby mode
- To provide an alternate path for load turnoff
- To help power distribution and sequencing

High-current motor drive systems use a discrete MOSFET as the power switch because integrated switch devices are limited in the power that they can drive. High-current motor drive systems can drive motors over 500 W.



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High-current motor-drive systems can use power switches to reduce the quiescent current in standby mode and an alternate path for load turn-off. However, because the motor output can be >500 W, the pass element of the power switch must be a discrete MOSFET because integrated switch devices are limited in the power that they can drive. These systems will implement the power switch in series with the supply (as opposed to on the return ground path) to prevent the switch from interfering with the complexity of the motor-drive circuit grounding.

The term “power switch” (or “load switch”) is a general term. This document uses the term "cut-off switch” to describe a high-side discrete MOSFET power switch.

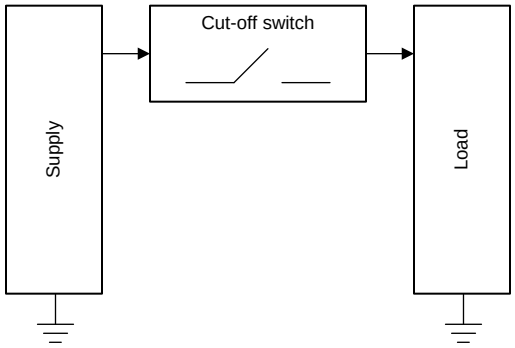


**Figure 1. Cut-Off Switch**

## 2 The Discrete PMOS Cut-Off Switch

The P-channel MOSFET (PMOS) is the simplest cut-off switch implementation, but there are two primary disadvantages. A PMOS is more expensive than N-channel MOSFETs (NMOS). The maximum power that can be achieved with PMOS solutions is limited (because the $R_{DS(ON)}$ of PMOS is higher than NMOS.) For very-high-power and cost-sensitive systems this circuit does not provide a good solution.

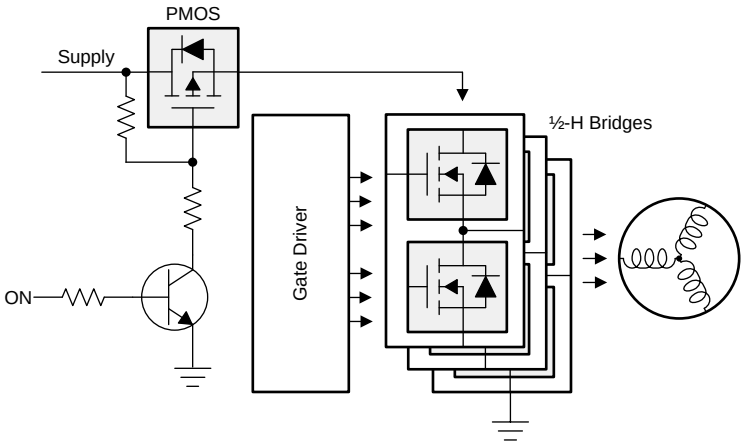


**Figure 2. Discrete PMOS Cut-Off Switch**

## 3 The Discrete NMOS Cut-Off Switch

The alternative is to use an NMOS as the pass element to prevent cost and power concerns of a PMOS. The major disadvantage of using the NMOS is that they will require a positive $V_{GS}$ (gate-to-source) to turn on. An external boost circuit (either DC/DC or charge pump) must be used to generate a gate drive voltage that is greater than the supply. The requirement of an additional voltage regulator adds significant design complexity and cost.



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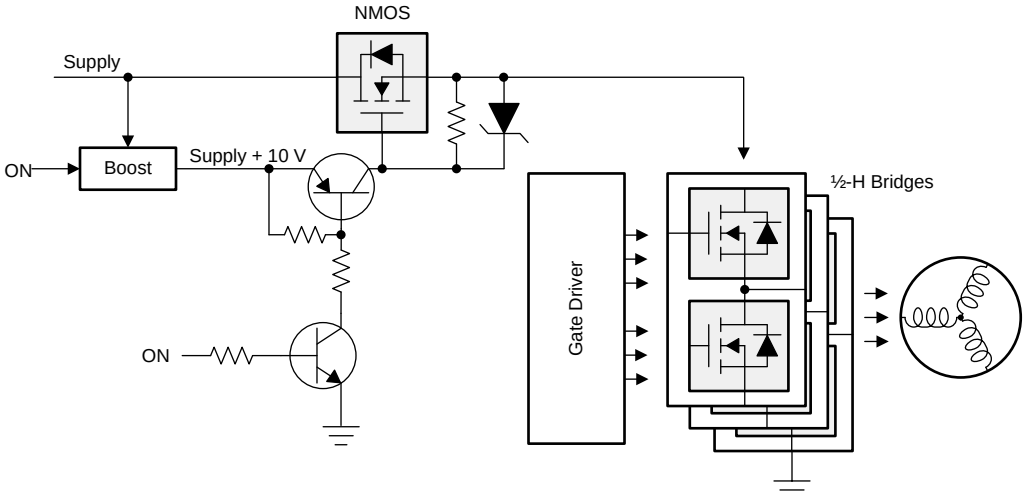


**Figure 3. Discrete NMOS Cut-Off Switch**

## 4 The Upstream NMOS Cut-Off Switch

Some solutions use a high-side gate driver (or controller) that removes the need for an external boost circuit. This solution is “upstream” because the gate drive voltage comes from the supply. A gate driver designed for this purpose can also integrate supply monitoring to provide protection against overvoltage and overcurrent events. For example, the TPS2492 device has system power limiting as well as a current monitor output, so a microcontroller can measure the current flowing through the cut-off switch when it is closed.

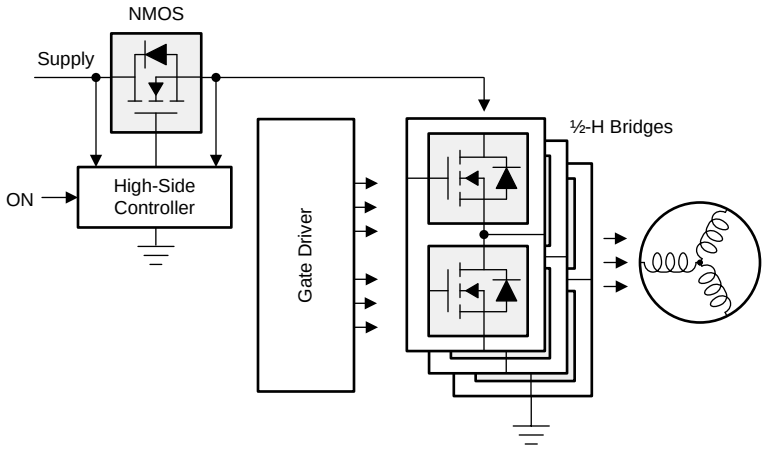


**Figure 4. Upstream NMOS Cut-Off Switch**

**Table 1. Device Options**

| Product | Maximum Voltage | Description |
|---|---|---|
| LM5060 | 65 V | High-Side Protection Controller with Low Quiescent Current |
| LM5069 | 65 V | High-Side Protection Controller with Low Quiescent Current with Power Limiting |
| TPS2490, TPS2491 | 80 V | Positive High-Voltage Power-Limiting Controller |
| TPS2492/3 | 80 V | Positive High-Voltage Power-Limiting Controller with Analog Current Monitor Output |


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## 5 The NMOS Cut-Off Switch With Downstream Motor Driver

To achieve a hybrid solution between the completely-discrete and fully-integrated solution, the designer can first look to solve the problem of Supply + 10 V to turn on the NMOS. In many motor drive applications, NMOS are already used for high-side MOSFETs in a ½-h bridge configuration. Most motor gate drivers integrate a boost circuit or charge pump to turn on the high-side NMOS. The designer can potentially use this “downstream” supply to power our high-side cut-off switch.

The gate voltage on the NMOS must be a Supply + 10 V to close the cut-off switch. The cut-off switch can be closed indefinitely which requires a constant voltage. Because of this, gate drivers that use a bootstrap architecture cannot be used because they do not generate the needed constant voltage above the supply.

If a charge pump is downstream, the system must have a way to turn on before the charge pump is active. Adding two diodes to the discrete NMOS circuit lets the system power up before the charge pump is active. These diodes will OR the system supply with the charge pump. When the cut-off switch is activated, the NMOS will act as a diode because the gate and drain are effectively shorted. After the motor gate driver has powered up, the charge pump will override the supply, and the NMOS will be fully enhanced.

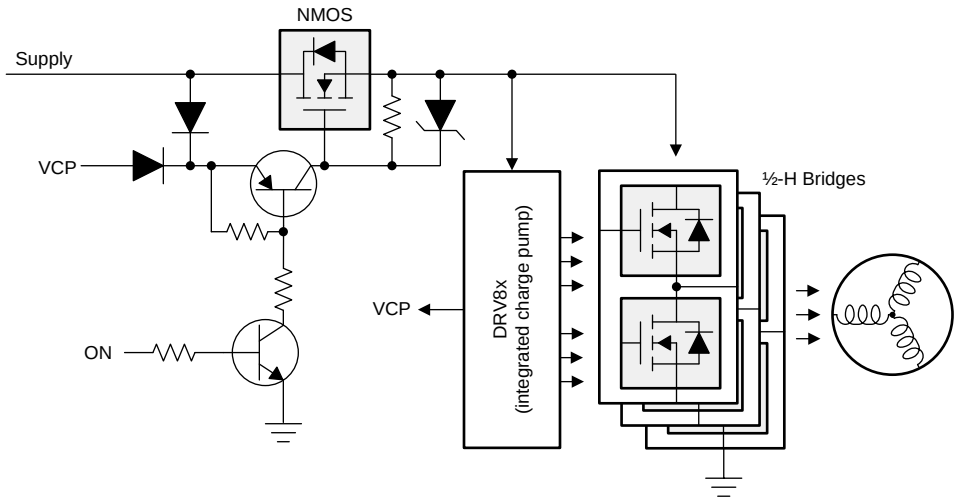


**Figure 5. NMOS Cut-Off Switch With Downstream Motor Driver**

**Table 2. Device Options**

| Product | Maximum Voltage | Description |
|---|---|---|
| DRV3205-Q1 | 60 V | Automotive Gate Driver with Three Current Shunt Amps and Enhanced Protection and Diagnostics |
| DRV3245Q-Q1 | 45 V | Automotive Gate Driver Unit (GDU) With High Performance Sensing, Protection and Diagnostics |
| DRV8304 | 38 V | Three-Phase Smart Gate Driver With Three Current Shunt Amplifiers |
| DRV8305 | 45 V | Three Phase Gate Driver with Three Integrated Current Shunt Amplifiers |
| DRV8305-Q1 | 45 V | Automotive Three Phase Gate Driver with Three Integrated Current Shunt Amplifiers |
| DRV8306 | 38 V | Brushless-DC Smart Gate Driver With Trapezoidal Commutation |
| DRV8320, DRV8320R, DRV8323, DRV8323R | 60 V | Three-Phase Smart Gate Driver With Optional Buck Regulator and Optional Three Current Shunt Amplifiers |
| DRV8350, DRV8350R, DRV8353, DRV8353R | 100 V | Three-Phase Smart Gate Driver With Optional Buck Regulator and Optional Three Current Shunt Amplifiers |
| DRV8701 | 45 V | Brushed DC Motor Gate Driver |
| DRV8702-Q1, DRV8703-Q1 | 45 V | Automotive Brushed DC Motor Gate Driver |


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## 6 References

- Texas Instruments, *Basics of Power Switches* application report

## Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| Changes from Original (July 2018) to A Revision | Page |
|---|---|
| • Added the DRV835x devices to the *Device Options* table | 4 |


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